# 

### BAV99T

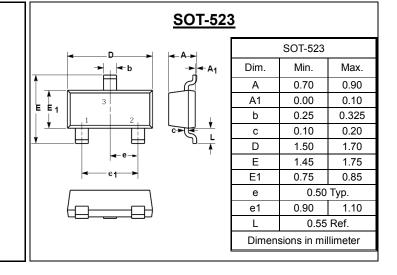
#### SURFACE MOUNT FAST SWITCHING DIODE

#### FEATURES

- Fast switching speed
- · Ideally suited for automatic insertion
- For general purpose switching applications

#### **MECHANICAL DATA**

- Case: SOT-523 Plastic
- Case material: "Green" molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl)
- Moisture sensitivity: Level 1 per J-STD-020D
- Lead free in RoHS 2002/95/EC compliant



**REVERSE VOLTAGE – 85 Volts** 

FORWARD CURRENT – 0.075 Ampere

#### Maximum Ratings & Thermal Characteristics @ $T_A = 25^{\circ}C$ unless otherwise specified

Characteristic		Symbol	BAV99T	Units
Working Peak Reverse Voltage DC Blocking Voltage		V <sub>R</sub>	85	V
Average Rectified Output Current		Ι <sub>Ο</sub>	75	mA
Non-Repetitive Peak Forward Surge Current	@t=1.0us	I <sub>FSM</sub>	4	А
Power Dissipation		P <sub>D</sub>	200	mW
Thermal Resistance Junction to Ar	nbient	Reja	625	°C <b>/W</b>
Operating Temperature Range		TJ	150	°C
Storage Temperature Range		T <sub>STG</sub>	-65~+150	°C

#### **Electrical Characteristics** @ $T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Test Condition	Symbol	Min.	Тур.	Max.	Unit
Reverse Breakdown Voltage	I <sub>R</sub> = 1uA	V <sub>BR</sub>	85			V
Movieure Forward ) (altono	$I_F = 1mA$ $I_F = 10mA$	N			715 855	
Maximum Forward Voltage	$I_{F} = 50mA$ $I_{F} = 150mA$	V <sub>F</sub>			1000 1250	mV
Maximum DC Reverse Current at Rated DC Blocking Voltage	V <sub>R</sub> = 75V V <sub>R</sub> = 25V	I <sub>R</sub>			2 0.03	uA
Typical Diode Capacitance	V <sub>R</sub> =0V,f=1MHz	CD			1.5	pF
Reverse Recovery time	Irr=1mA, I <sub>R</sub> =I <sub>F</sub> =10mA R <sub>L</sub> =100Ω	trr			4	ns
				BEV	. 2. Oct-2010. k	SVR43

REV. 2, Oct-2010, KSYR43

## RATING AND CHARACTERISTIC CURVES BAV99T

#### Fig.1 Current Derating Curve **Fig.2 Typical Forward Characteristics** I<sub>F</sub>, INSTANTANEOUS FORWARD CURRENT (A) 1000 300 250 IF, FORWARD CURRENT (mA) 200 T<sub>A</sub> = 150°C Single diode loaded T<sub>A</sub> = 75°C 25°C 150 0°C 1 = -40°C ТΑ 100 Double diode loaded 50 0 0 50 100 150 200 0 0.5 1.0 1.5 T<sub>s</sub>, SOLDERING POINT TEMPERATURE VF, INSTANTANEOUS FORWARD VOLTAGE (V) Fig.3 Typical Reverse Characteristics 10,000 IR, INSTANTANEOUS REVERSE CURRENT (nA) = 150°C r<sub>A</sub> = 125°C 1,000 100 T<sub>A</sub> = 75°C = 25°C 10 T<sub>A</sub> = 0°C 1 -40°C = 0.1 ł 0 20 40 60 80 100 V<sub>R</sub>, INSTANTANEOUS REVERSE VOLTAGE (V)

TEON

#### **Device Marking :**

Device P/N	Marking code	Equivalent Circuit Diagram
BAV99T	JE	3 <b>0- 0</b> 1



### **Important Notice and Disclaimer**

LSC reserves the right to make changes to this document and its products and specifications at any time without notice. Customers should obtain and confirm the latest product information and specifications before final design, purchase or use.

LSC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does LSC assume any liability for application assistance or customer product design. LSC does not warrant or accept any liability with products which are purchased or used for any unintended or unauthorized application.

No license is granted by implication or otherwise under any intellectual property rights of LSC.

LSC products are not authorized for use as critical components in life support devices or systems without express written approval of LSC.